

FMSNP3401-Q1-H

List

List.....1

Package outline.....2

Features.....2

Applications.....2

Mechanical data.....2

Maximum ratings2

Electrical characteristics.....3

Rating and characteristic curves.....4

Pinning information.....5

Marking.....5

Suggested solder pad layout.....5

Packing Information.....6

Reel Packing.....7

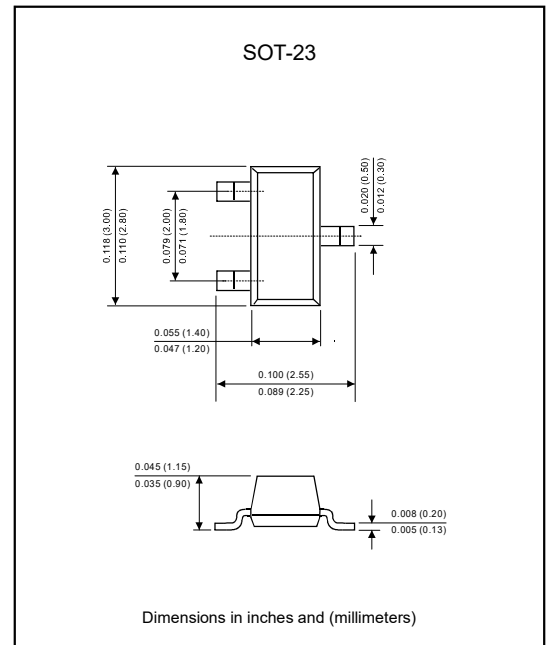
Suggested thermal profiles for soldering processes.....7

FMSNP3401-Q1-H**-4.2A -30V P-Channel Trench
Enhancement Mode MOSFET****Features**

- $-V_{DS} = 30V$, $-I_D = 4.2A$.
- $R_{DS(ON)} \leq 65m\Omega$, @ $-V_{GS} = 10V$, $-I_D = 4.2A$.
- $R_{DS(ON)} \leq 75m\Omega$, @ $-V_{GS} = 4.5V$, $-I_D = 4.0A$.
- $R_{DS(ON)} \leq 90m\Omega$, @ $-V_{GS} = 2.5V$, $-I_D = 1.0A$.
- -Q1 for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- Lead-free parts meet RoHS requirements.
- Halogen-free (IEC61249-2-21).

Mechanical data

- Epoxy: UL94-V0 rated flame retardant
- Case : Molded plastic, SOT-23
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Mounting Position : Any
- Weight : Approximated 0.008 gram

Package outline**Maximum ratings** ($T_J = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Ratings	Unit
Drain-source voltage	$-V_{DS}$	30	V
Gate-source voltage	V_{GS}	± 12	V
Continuous drain current ($T_A = 25^\circ C$)	$-I_D$	4.2	A
Continuous drain current ($T_A = 70^\circ C$)		3.5	
Pulsed drain current	$-I_{DM}$	30	A
Power dissipation	P_D	350	mW
Operating Junction temperature range	T_J	+150	$^\circ C$
Storage temperature range	T_{STG}	-55 to +150	$^\circ C$
Thermal resistance Junction to ambient	$R_{\theta JA}$	357	$^\circ C/W$

FMSNP3401-Q1-H

Electrical characteristics (At $T_j=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Off characteristics						
Drain-source breakdown voltage	$-BV_{\text{DSS}}$	$-I_{\text{D}} = 250\mu\text{A}$, $V_{\text{GS}} = 0\text{V}$	30			V
Drain-source leakage current	$-I_{\text{DSS}}$	$-V_{\text{DS}} = 24\text{V}$, $V_{\text{GS}} = 0\text{V}$			1	μA
Gate-source leakage current	I_{GSS}	$V_{\text{GS}} = \pm 12\text{V}$, $V_{\text{DS}} = 0\text{V}$			± 100	nA
On characteristics						
Gate threshold voltage	$-V_{\text{GS(TH)}}$	$V_{\text{DS}} = V_{\text{GS}}$, $-I_{\text{D}} = 250\mu\text{A}$	0.7	0.9	1.3	V
Forward transconductance (Note 1)	g_{FS}	$-V_{\text{DS}} = 5\text{V}$, $-I_{\text{D}} = 5\text{A}$	7			S
Static drain-source on-resistance (Note 1)	$R_{\text{DS(ON)}}$	$-V_{\text{GS}} = 10\text{V}$, $-I_{\text{D}} = 4.2\text{A}$		50	65	m Ω
		$-V_{\text{GS}} = 4.5\text{V}$, $-I_{\text{D}} = 4\text{A}$		60	75	
		$-V_{\text{GS}} = 2.5\text{V}$, $-I_{\text{D}} = 1\text{A}$		75	90	
Dynamic Parameters						
Input capacitance	C_{iss}	$V_{\text{GS}} = 0\text{V}$, $-V_{\text{DS}} = 15\text{V}$, $f = 1.0\text{MHz}$		954		pF
Output capacitance	C_{oss}			115		
Reverse transfer capacitance	C_{rss}			77		
Switching parameters						
Turn-on delay time	$t_{\text{D(ON)}}$	$-V_{\text{DS}} = 15\text{V}$, $-V_{\text{GS}} = 10\text{V}$, $R_{\text{G}} = 6\Omega$, $R_{\text{L}} = 3.6\Omega$		6.3		ns
Rise time	t_{r}			3.2		
Turn-off delay time	$t_{\text{D(OFF)}}$			38.2		
Fall time	t_{f}			12		
Source-drain diode ratings and characteristics (Note2)						
Drain - source diode forward voltage (Note 1)	$-V_{\text{SD}}$	$-I_{\text{S}} = 1\text{A}$, $V_{\text{GS}} = 0\text{V}$			1.0	V

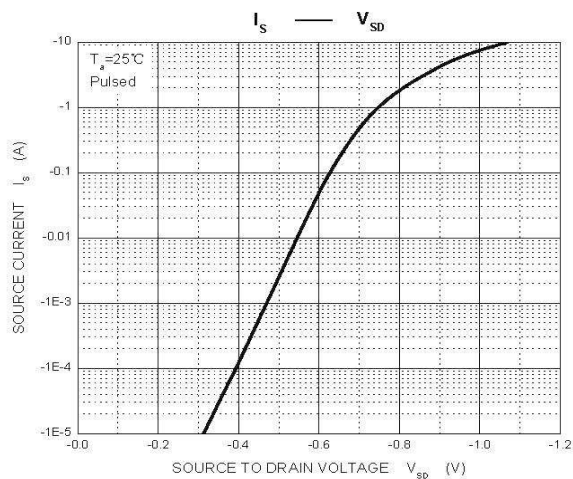
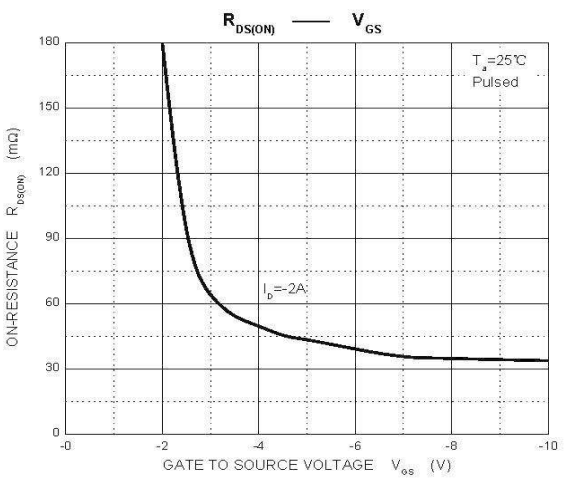
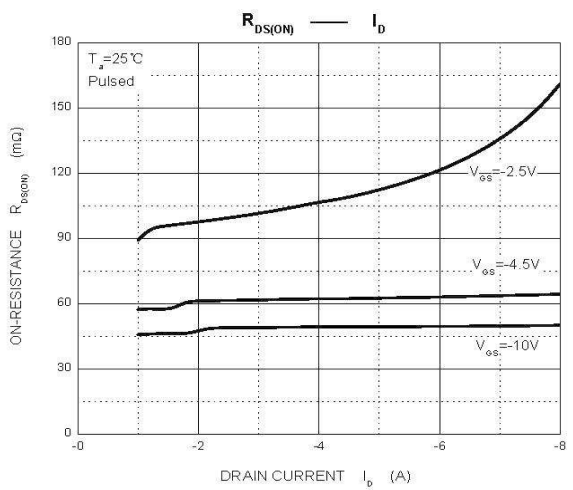
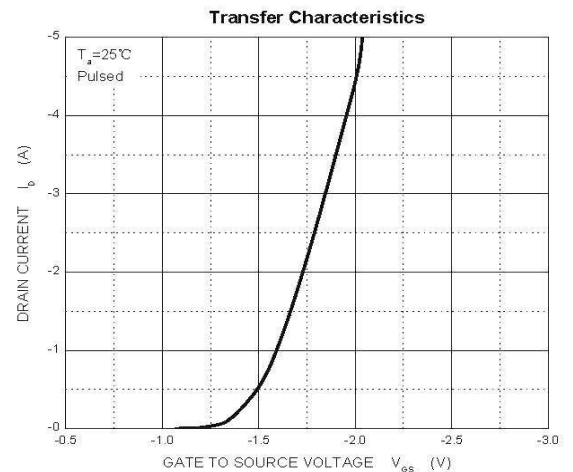
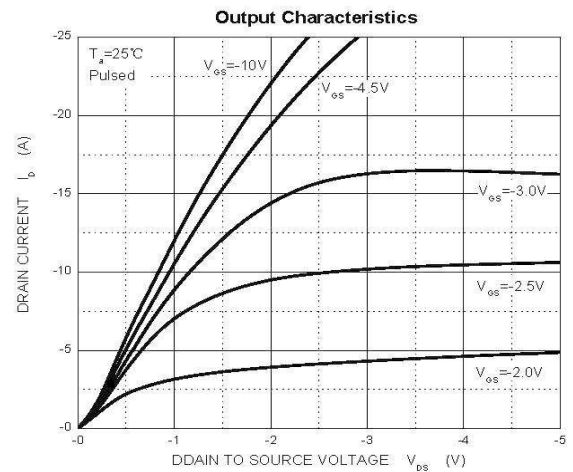
Note :

1. Pulse test: Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

2. These parameters have no way to verify.

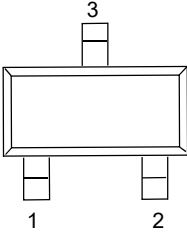
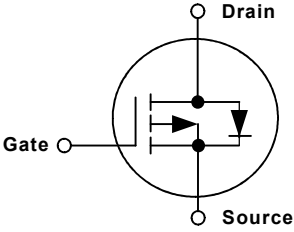
FMSNP3401-Q1-H

Rating and characteristic curves



FMSNP3401-Q1-H

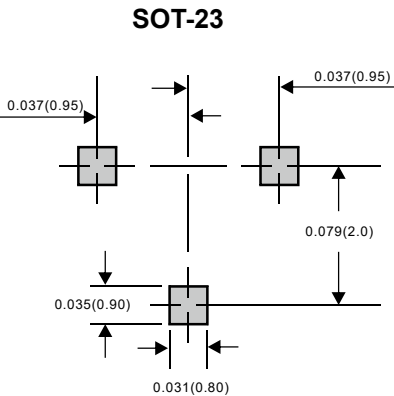
Pinning information

Pin	Simplified outline	Symbol
Pin 1 Gate Pin 2 Source Pin 3 Drain		

Marking

Type number	Marking Code
FMSNP3401-Q1-H	$\overline{\text{R1}}$

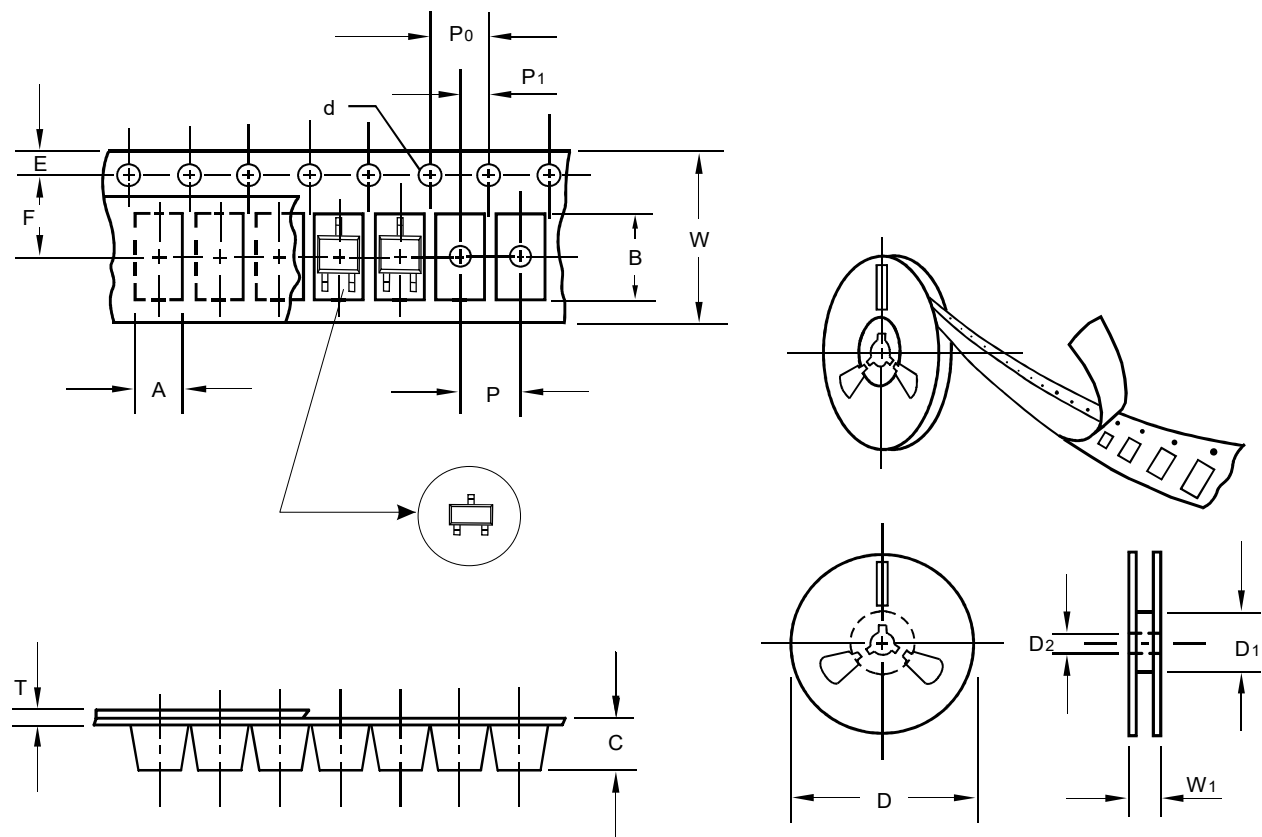
Suggested solder pad layout



Dimensions in inches and (millimeters)

FMSNP3401-Q1-H

Packing information



unit:mm

Item	Symbol	Tolerance	SOT-23
Carrier width	A	0.1	3.15
Carrier length	B	0.1	2.77
Carrier depth	C	0.1	1.22
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	54.40
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	11.40

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

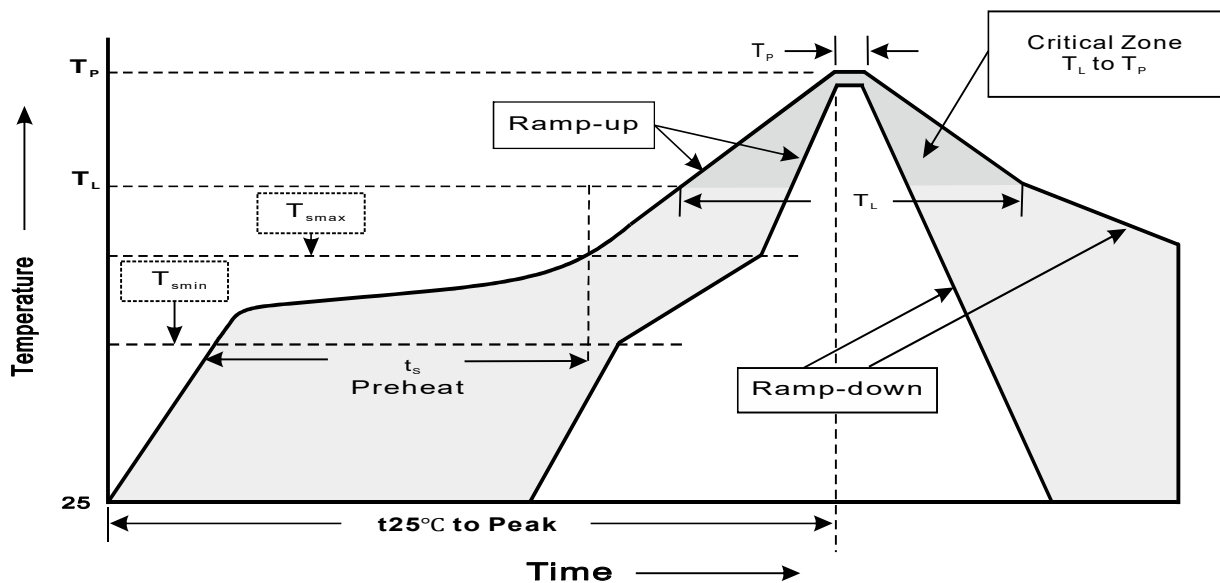
FMSNP3401-Q1-H

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-23	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000	11.6

Suggested thermal profiles for soldering processes

- Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- Reflow soldering of surface-mount devices



3. Reflow soldering

Profile feature	Soldering Condition
Average ramp-up rate (T_L to T_P)	< 3°C/sec
Preheat -Temperature Min (T_{smin}) -Temperature Max (T_{smax}) -Time (min to max) (t_s)	150°C 200°C 60 ~ 120sec
T_{smax} to T_L -Ramp-up rate	< 3°C/sec
Time maintained above: -Temperature (T_L) -Time(T_L)	217°C 60 ~ 260 sec
Peak Temperature(T_P)	255°C -0/+5°C
Time within 5°C of actual peak Temperature(T_P)	10 ~ 30sec
Ramp-down rate	< 6°C/sec
Time 25°C to peak temperature	< 6 minutes